

4th Generation 1200 V, 30 A Silicon Carbide Schottky Diode

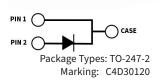
Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.









Features

- Low Forward Voltage (V_F) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior

Typical Applications

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

Maximum Ratings (T_c = 25°C Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V _{RRM}	1200	V			
DC Blocking Voltage	V _{DC}	1200	V			
		94		T _c = 25 °C		
Continuous Forward Current	I _F	45		T _c = 135 °C	Fig. 3	
		30	А	T _c = 155 °C		
Repetitive Peak Forward Surge Current	I _{FRM}	121		T _c = 25 °C, t _p = 10 ms, Half Sine Wave		
		68		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, Half Sine Wave}$		
Non-Repetitive Forward Surge Current	 FSM	233		T _c = 25 °C, t _p = 10 ms, Half Sine Wave	Fig. 8	
		209		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, Half Sine Wave}$		
i²t Value	∫i²t	271		$T_{c} = 25 {}^{\circ}\text{C}, t_{p} = 10 \text{ms}$		
		218		$T_{c} = 110 {\rm ^{\circ}C}, t_{p} = 10 {\rm ms}$		
Power Dissipation	P _{tot}	441	W	T _c = 25 °C	Fig. 4	
		191		T _c = 110 °C		

Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes	
Forward Voltage	, v	1.5	1.8	V	I _F = 30 A, T _i = 25 °C	Fi- 1	
	V _F	2.2	3		I _F = 30 A, T _j = 175 °C	Fig. 1	
Dovorco Current		40	250		V _R = 1200 V, T _j = 25 °C	Fig. 2	
Reverse Current	I _R	70	450	μΑ	V _R = 1200 V, T _j = 175 °C	Fig. 2	
Total Capacitive Charge	Q _c	152		nC	V _R = 800 V, T _j = 25 °C	Fig. 5	
		2177			$V_R = 0 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$		
Total Capacitance	С	136		pF	$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	Fig. 6	
		100			V _R = 800 V, T _j = 25 °C, f = 1 MHz		
Capacitance Stored Energy	E _c	44		μJ	V _R = 800 V	Fig. 7	

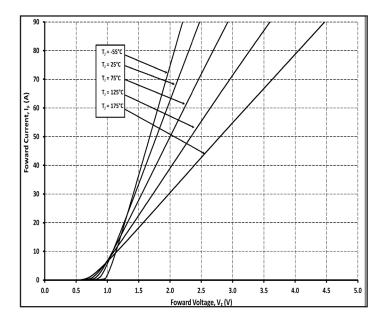
Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	R _{0, JC (TYP)}	0.34	°C/W	
Junction Temperature	T _j	-55 to +175	°C —	
Case & Storage Temperature	T _c	-55 to +150		
TO 247 Maunting Tayous		1	Nm	M3 Screw
TO-247 Mounting Torque	-	8.8	lbf-in	6-32 Screw

Typical Performance



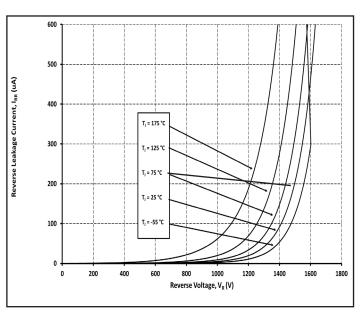
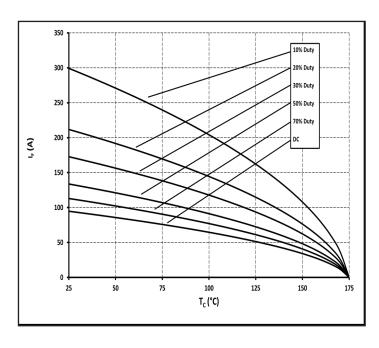


Figure 1. Forward Characteristics

Figure 2. Reverse Characteristics



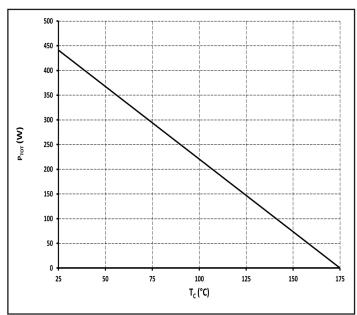
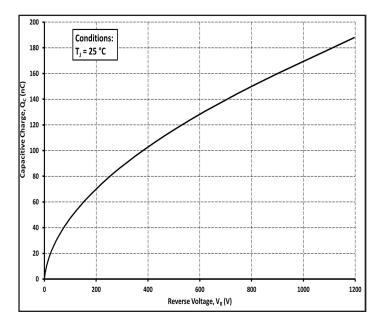


Figure 3. Current Derating

Figure 4. Power Derating

Typical Performance



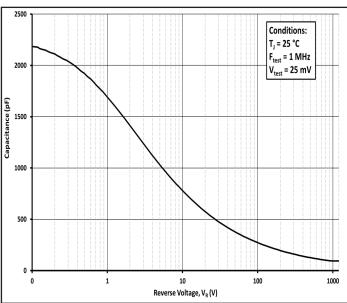
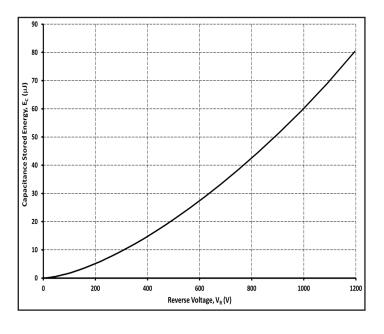


Figure 5.
Total Capacitance Charge vs. Reverse Voltage

Figure 6.
Capacitance vs. Reverse Voltage



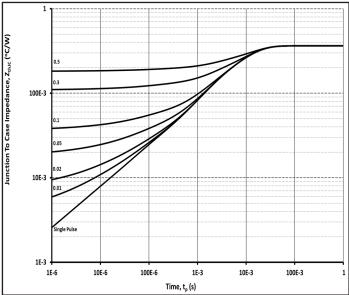
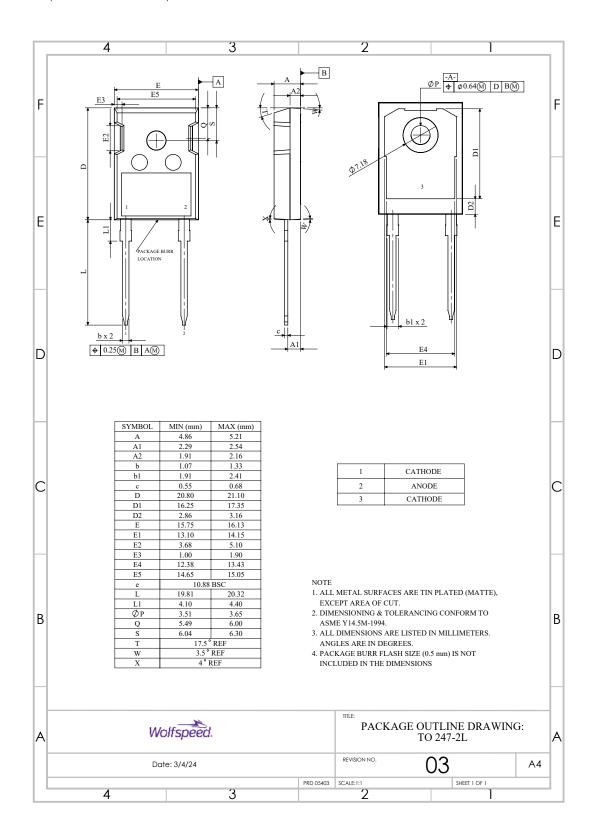


Figure 7.
Typical Capacitance Stored Energy

Figure 8. Transiant Thermal Impedence

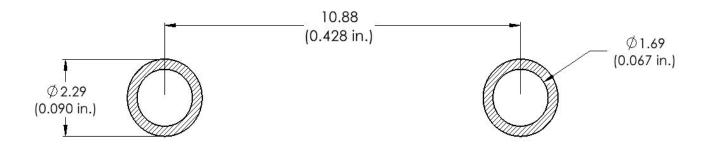
Package Dimensions & Pin-Out

Package: TO-247-2 (All dimensions are in mm)



Recommended Solder Pad Layout

(All dimensions are in mm)



Product Ordering Information

Order Number	Packing Type
C4D30120H	Tube

REACh, RoHS, and Halogen-Free compliance documentation available for this product.

Revision History

Document Version	Date of Release	Description of changes
0	January - 2019	Initial Release
1	January - 2023	Updated POD and Landing Pad
2	August - 2024	Notes and dislaimers, added ROHS and Halogen Free Symbols, package marking corrected

Notes & Disclaimer

WOLFSPEED PROVIDES TECHNICAL AND RELIABILITY DATA, DESIGN RESOURCES, APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, WITH RESPECT THERETO, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, SUITABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

This document and the information contained herein are subject to change without notice. Any such change shall be evidenced by the publication of an updated version of this document by Wolfspeed. No communication from any employee or agent of Wolfspeed or any third party shall effect an amendment or modification of this document. No responsibility is assumed by Wolfspeed for any infringement of patents or other rights of third parties which may result from use of the information contained herein. No license is granted by implication or otherwise under any patent or patent rights of Wolfspeed.

The information contained in this document (excluding examples, as well as figures or values that are labeled as "typical") constitutes Wolfspeed's sole published specifications for the subject product. "Typical" parameters are the average values expected by Wolfspeed in large quantities and are provided for informational purposes only. Any examples provided herein have not been produced under conditions intended to replicate any specific end use. Product performance can and does vary due to a number of factors.

This product has not been designed or tested for use in, and is not intended for use in, any application in which failure of the product would reasonably be expected to cause death, personal injury, or property damage. For purposes of (but without limiting) the foregoing, this product is not designed, intended, or authorized for use as a critical component in equipment implanted into the human body, life-support machines, cardiac defibrillators, and similar emergency medical equipment; air traffic control systems; or equipment used in the planning, construction, maintenance, or operation of nuclear facilities. Notwithstanding any application-specific information, guidance, assistance, or support that Wolfspeed may provide, the buyer of this product is solely responsible for determining the suitability of this product for the buyer's purposes, including without limitation (1) selecting the appropriate Wolfspeed products for the buyer's application, (2) designing, validating, and testing the buyer's application, and (3) ensuring the buyer's application meets applicable standards and any other legal, regulatory, and safety-related requirements.

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Wolfspeed representative or from the Product Documentation sections of www.wolfspeed. com.

REACh Compliance

REACh substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact your Wolfspeed representative to ensure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

Contact info:

4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.wolfspeed.com/power

© 2024 Wolfspeed, Inc. All rights reserved. Wolfspeed® and the Wolfstreak logo are registered trademarks and the Wolfspeed logo is a trademark of Wolfspeed, Inc. PATENT: https://www.wolfspeed.com/legal/patents

The information in this document is subject to change without notice.